T1210H-8F 12A TRIAC

Rev.A.1.1

DESCRIPTION:

The T1210H-8F triac i ` M \

ORDERING INFORMATION

T 12 10 H -8 F

- T: Triacs
- 12: $I_{T(RMS)}$:12A
- 10: $I_{GT1-3} \leq 10mA$
- H: High junction temperature
- -8: V_{DRM} /$V_{RRM} \geq 800V$
- F: TO-220F(Ins)

MARKING

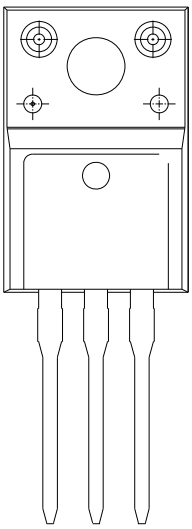


FIG.1: Maximum power dissipation versus RMS on-state current

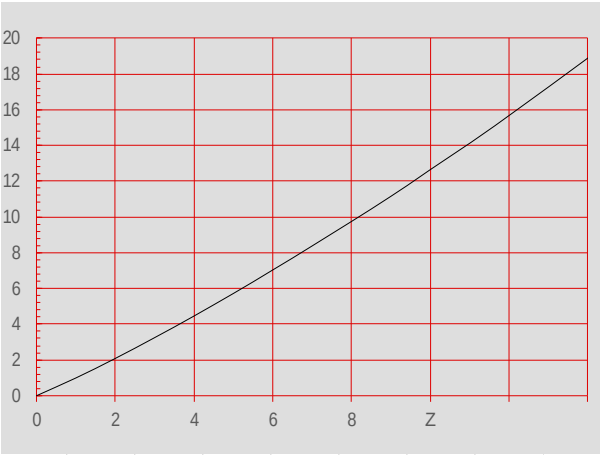
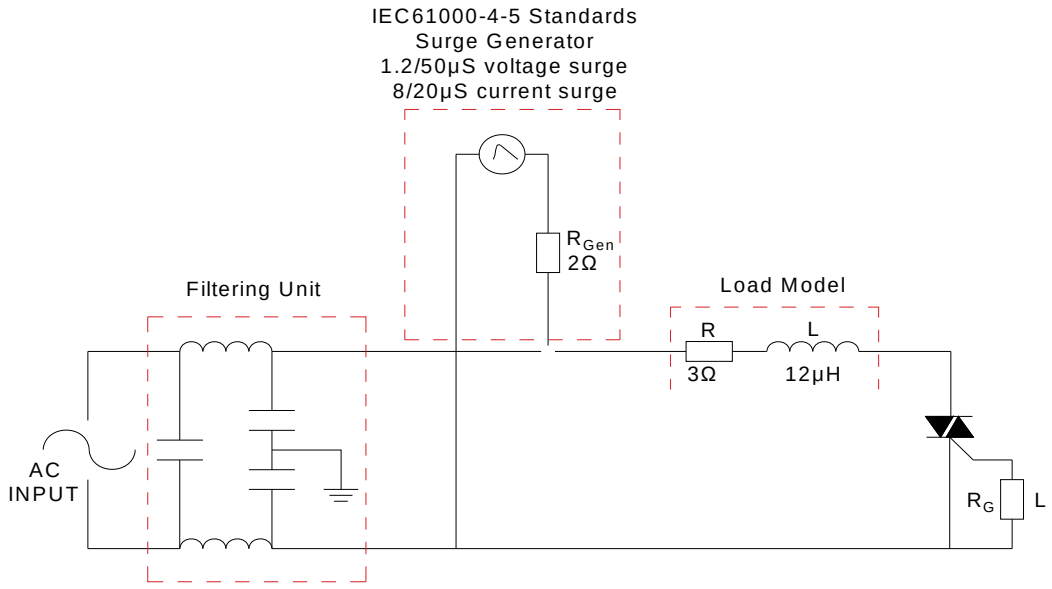


FIG.2: RMS on-state current versus case temperature

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FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



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